

## LMH6570 2:1 High Speed Video Multiplexer

Check for Samples: [LMH6570](#)

### FEATURES

- 500 MHz, 500 mV<sub>PP</sub>, –3 dB Bandwidth, A<sub>V</sub>=2
- 400 MHz, 2V<sub>PP</sub>, –3 dB Bandwidth, A<sub>V</sub>=2
- 8 ns Channel Switching Time
- 70 dB Channel to Channel Isolation @ 10 MHz
- 0.02%, 0.05° Diff. Gain, Diff. Phase
- 0.1 dB Gain Flatness to 150 MHz
- 2200 V/μs Slew Rate
- Wide Supply Voltage Range: 6V (±3V) to 12V (±6V)
- –68 dB HD2 @ 5 MHz
- –84 dB HD3 @ 5 MHz

### APPLICATIONS

- Video Router
- Multi Input Video Monitor
- Instrumentation / Test Equipment
- Receiver IF Diversity Switch
- Multi Channel A/D Driver
- Picture in Picture Video Switch

### Connection Diagram

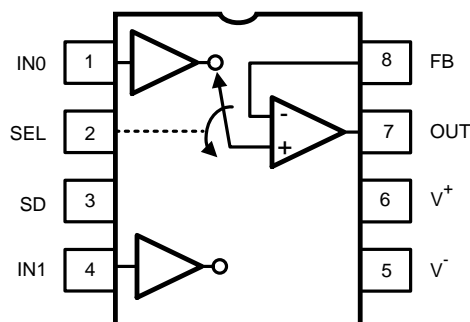


Figure 1. 8-Pin SOIC - Top View  
See D Package

### Truth Table

SEL	SD	OUTPUT
1	0	IN1 * (1+RF/RG)
0	0	IN0 * (1+RF/RG)
X	1	Shutdown



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### Absolute Maximum Ratings<sup>(1)(2)</sup>

ESD Tolerance <sup>(3)</sup>	Human Body Model	2000V
	Machine Model	200V
Supply Voltage ( $V^+ - V^-$ )		13.2V
$I_{OUT}$ <sup>(4)</sup>		130 mA
Signal & Logic Input Pin Voltage		$\pm(V_S+0.6V)$
Signal & Logic Input Pin Current		$\pm 20$ mA
Maximum Junction Temperature		+150°C
Storage Temperature Range		-65°C to +150°C
Soldering Information: See <a href="#">SNOA549</a>		

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For specifications, see the Electrical Characteristics tables.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) Human Body model, 1.5k $\Omega$  in series with 100 pF. Machine model, 0 $\Omega$  in series with 200 pF
- (4) The maximum output current ( $I_{OUT}$ ) is determined by the device power dissipation limitations (The junction temperature cannot be allowed to exceed 150°C). See **POWER DISSIPATION** of the [Application Notes](#) for more details. A short circuit condition should be limited to 5 seconds or less.

### Operating Ratings<sup>(1)</sup>

Operating Temperature			-40 °C to 85 °C
Supply Voltage Range			6V to 12V
Thermal Resistance	Package	( $\theta_{JA}$ )	150°C/W
	8-Pin SOIC	( $\theta_{JC}$ )	50°C/W

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For specifications, see the Electrical Characteristics tables.

### $\pm 5V$ Electrical Characteristics

$V_S = \pm 5V$ ,  $R_L = 100\Omega$ ,  $R_F = 576\Omega$ ,  $A_V = 2$  V/V,  $T_J = 25$  °C, Unless otherwise specified. **Bold** numbers specify limits at temperature extremes.

Symbol	Parameter	Conditions <sup>(1)</sup>	Min <sup>(2)</sup>	Typ <sup>(3)</sup>	Max <sup>(2)</sup>	Units
<b>Frequency Domain Performance</b>						
SSBW	-3 dB Bandwidth	$V_{OUT} = 0.5 V_{PP}$		500		MHz
LSBW	-3 dB Bandwidth	$V_{OUT} = 2 V_{PP}$ <sup>(4)</sup>		400		MHz
.1 dBBW	0.1 dB Bandwidth	$V_{OUT} = 0.25 V_{PP}$		150		MHz
DG	Differential Gain	$R_L = 150\Omega$ , $f = 4.43$ MHz		0.02		%
DP	Differential Phase	$R_L = 150\Omega$ , $f = 4.43$ MHz		0.05		deg
XTLK	Channel to Channel Crosstalk	All Hostile, $f = 5$ MHz		-70		dBc
<b>Time Domain Response</b>						
TRS	Channel to Channel Switching Time	Logic transition to 90% output		8		ns
	Enable and Disable Times	Logic transition to 90% or 10% output.		10		ns
TRL	Rise and Fall Time	4V Step		2.4		ns

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that  $T_J = T_A$ . No specification of parametric performance is indicated in the electrical tables under conditions of internal self heating where  $T_J > T_A$ . See [Application Notes](#) for information on temperature de-rating of this device. Min/Max ratings are based on product testing, characterization and simulation. Individual parameters are tested as noted.
- (2) Limits are 100% production tested at 25°C. Limits over the operating temperature range are ensured through correlation using Statistical Quality Control (SQC) methods.
- (3) Typical numbers are the most likely parametric norm.
- (4) Parameter ensured by design.

**±5V Electrical Characteristics (continued)**
 $V_S = \pm 5V$ ,  $R_L = 100\Omega$ ,  $R_F = 576\Omega$ ,  $A_V = 2 V/V$ ,  $T_J = 25^\circ C$ , Unless otherwise specified. **Bold** numbers specify limits at temperature extremes.

Symbol	Parameter	Conditions <sup>(1)</sup>	Min <sup>(2)</sup>	Typ <sup>(3)</sup>	Max <sup>(2)</sup>	Units
TSS	Settling Time to 0.05%	2V Step		17		ns
OS	Overshoot	2V Step		5		%
SR	Slew Rate	4V Step <sup>(4)(5)</sup>		2200		V/ $\mu$ s
<b>Distortion</b>						
HD2	2 <sup>nd</sup> Harmonic Distortion	2 V <sub>PP</sub> , 5 MHz		-68		dBc
HD3	3 <sup>rd</sup> Harmonic Distortion	2 V <sub>PP</sub> , 5 MHz		-84		dBc
IMD	3 <sup>rd</sup> Order Intermodulation Products	10 MHz, Two tones 2 V <sub>pp</sub> at output		-80		dBc
<b>Equivalent Input Noise</b>						
VN	Voltage	>1 MHz, Input Referred		5		nV/ $\sqrt{Hz}$
ICN	Current	>1 MHz, Input Referred		5		pA/ $\sqrt{Hz}$
<b>Static, DC Performance</b>						
CHGM	Channel to Channel Gain Difference	DC, Difference in gain between channels		±0.005	±0.034 <b>±0.036</b>	%
VIO	Input Offset Voltage	V <sub>IN</sub> = 0V		1	±15 <b>±21</b>	mV
DVIO	Offset Voltage Drift <sup>(6)</sup>			30		$\mu$ V/ $^\circ C$
IBN	Input Bias Current <sup>(7)</sup>	V <sub>IN</sub> = 0V		-3	±8 <b>±10</b>	$\mu$ A
DIBN	Bias Current Drift <sup>(6)</sup>			11		nA/ $^\circ C$
IBI	Inverting Input Bias Current <sup>(8)</sup>	Pin 8, Feedback point, V <sub>IN</sub> = 0V		-3	±18 <b>±22</b>	$\mu$ A
PSRR	Power Supply Rejection Ratio	DC, Input referred	48 <b>46</b>	50		dB
ICC	Supply Current	No Load, Shutdown Pin (SD) > 0.8V		13.8	15 <b>16</b>	mA
	Supply Current Shutdown	Shutdown Pin (SD) > 2V		1.1	1.3 <b>1.4</b>	mA
VIH	Logic High Threshold	Select Pin & Shutdown pin (SEL, SD)	2.0			V
VIL	Logic Low Threshold	Select Pin & Shutdown pin (SEL, SD)			0.8	V
IiL	Logic Pin Input Current Low <sup>(8)</sup>	Logic Input = 0V Select Pin & Shutdown pin (SEL, SD)	-8 <b>-10</b>	-1		$\mu$ A
IiH	Logic Pin Input Current High <sup>(8)</sup>	Logic Input = 5.0V, Select Pin & Shutdown pin (SEL, SD)		57	68 <b>75</b>	$\mu$ A
<b>Miscellaneous Performance</b>						
RIN+	Input Resistance			5		k $\Omega$
CIN	Input Capacitance			0.8		pF
ROUT	Output Resistance	Output Active, (SD < 0.8V)		0.04		$\Omega$
ROUT	Output Resistance	Output Disabled, (SD > 2V)		3000		$\Omega$
COUT	Output Capacitance	Output Disabled, (SD > 2V)		3.1		pF
VO	Output Voltage Range	No Load	±3.51 <b>±3.50</b>	±3.7		V
VOL		R <sub>L</sub> = 100 $\Omega$	±3.16 <b>±3.15</b>	±3.5		V
CMIR	Input Voltage Range		±2.5	±2.6		V
IO	Linear Output Current <sup>(8)</sup>	V <sub>IN</sub> = 0V,	+60 -70 <b>±55</b>	±80		mA

(5) Slew Rate is the average of the rising and falling edges.

(6) Drift determined by dividing the change in parameter at temperature extremes by the total temperature change.

(7) Positive Value is current into device.

(8) Positive Value is current into device.

### ±5V Electrical Characteristics (continued)

$V_S = \pm 5V$ ,  $R_L = 100\Omega$ ,  $R_F = 576\Omega$ ,  $A_V = 2 V/V$ ,  $T_J = 25^\circ C$ , Unless otherwise specified. **Bold** numbers specify limits at temperature extremes.

Symbol	Parameter	Conditions <sup>(1)</sup>	Min <sup>(2)</sup>	Typ <sup>(3)</sup>	Max <sup>(2)</sup>	Units
ISC	Short Circuit Current <sup>(9)</sup>	$V_{IN} = \pm 2V$ , Output shorted to ground		<b>±230</b>		mA

(9) The maximum output current ( $I_{OUT}$ ) is determined by the device power dissipation limitations (The junction temperature cannot be allowed to exceed  $150^\circ C$ ). See **POWER DISSIPATION** of the **Application Notes** for more details. A short circuit condition should be limited to 5 seconds or less.

### ±3.3V Electrical Characteristics

$V_S = \pm 3.3V$ ,  $R_L = 100\Omega$ ,  $R_F = 576\Omega$ ,  $A_V = 2 V/V$ ; Unless otherwise specified.

Symbol	Parameter	Conditions <sup>(1)</sup>	Min <sup>(2)</sup>	Typ <sup>(3)</sup>	Max <sup>(2)</sup>	Units
<b>Frequency Domain Performance</b>						
SSBW	-3 dB Bandwidth	$V_{OUT} = 0.5 V_{PP}$		475		MHz
LSBW	-3 dB Bandwidth	$V_{OUT} = 2.0 V_{PP}$		375		MHz
0.1 dBBW	0.1 dB Bandwidth	$V_{OUT} = 0.5 V_{PP}$		100		MHz
GFP	Peaking	DC to 200 MHz		0.4		dB
XTLK	Channel to Channel Crosstalk	All Hostile, $f = 5$ MHz		-70		dBc
<b>Time Domain Response</b>						
TRL	Rise and Fall Time	2V Step		2		ns
TSS	Settling Time to 0.05%	2V Step		20		ns
OS	Overshoot	2V Step		5		%
SR	Slew Rate	2V Step		1400		V/ $\mu$ s
<b>Distortion</b>						
HD2	2 <sup>nd</sup> Harmonic Distortion	2 $V_{PP}$ , 10 MHz		-67		dBc
HD3	3 <sup>rd</sup> Harmonic Distortion	2 $V_{PP}$ , 10 MHz		-87		dBc
<b>Static, DC Performance</b>						
VIO	Input Offset Voltage	$V_{IN} = 0V$		1		mV
IBN	Input Bias Current <sup>(4)</sup>	$V_{IN} = 0V$		-3		$\mu$ A
PSRR	Power Supply Rejection Ratio	DC, Input Referred		49		dB
ICC	Supply Current	No Load		12.5		mA
VIH	Logic High Threshold	Select Pin & Shutdown pin (SEL, SD), $V_{IH} \approx V^+ * 0.4$		1.3		V
VIL	Logic Low Threshold	Select Pin & Shutdown pin (SEL, SD), $V_{IL} \approx V^+ * 0.12$		0.4		V
<b>Miscellaneous Performance</b>						
RIN+	Input Resistance			5		k $\Omega$
CIN	Input Capacitance			0.8		pF
ROUT	Output Resistance			0.06		$\Omega$
VO	Output Voltage Range	No Load		±2		V
VOL		$R_L = 100\Omega$		±1.8		V
CMIR	Input Voltage Range			±1.2		V
IO	Linear Output Current <sup>(5)</sup>	$V_{IN} = 0V$		±60		mA

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that  $T_J = T_A$ . No specification of parametric performance is indicated in the electrical tables under conditions of internal self heating where  $T_J > T_A$ . See **Application Notes** for information on temperature de-rating of this device. Min/Max ratings are based on product testing, characterization and simulation. Individual parameters are tested as noted.
- (2) Limits are 100% production tested at  $25^\circ C$ . Limits over the operating temperature range are ensured through correlation using Statistical Quality Control (SQC) methods.
- (3) Typical numbers are the most likely parametric norm.
- (4) Positive Value is current into device.
- (5) The maximum output current ( $I_{OUT}$ ) is determined by the device power dissipation limitations (The junction temperature cannot be allowed to exceed  $150^\circ C$ ). See **POWER DISSIPATION** of the **Application Notes** for more details. A short circuit condition should be limited to 5 seconds or less.

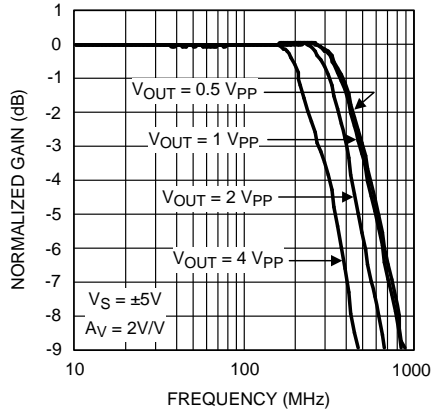
**±3.3V Electrical Characteristics (continued)**
 $V_S = \pm 3.3V$ ,  $R_L = 100\Omega$ ,  $R_F = 576\Omega$ ,  $A_V = 2 V/V$ ; Unless otherwise specified.

Symbol	Parameter	Conditions <sup>(1)</sup>	Min <sup>(2)</sup>	Typ <sup>(3)</sup>	Max <sup>(2)</sup>	Units
ISC	Short Circuit Current <sup>(5)</sup>	$V_{IN} = \pm 1V$ , Output shorted to ground		±150		mA

**Typical Performance Characteristics**

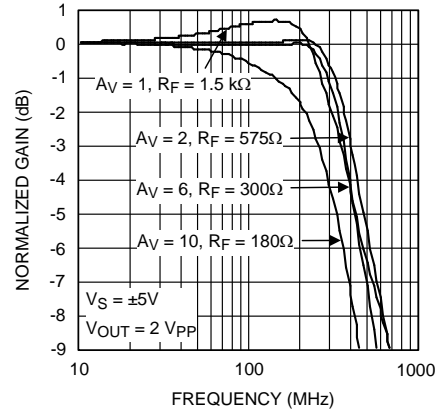
$V_s = \pm 5V$ ,  $R_L = 100\Omega$ ,  $A_V = 2$ ,  $R_F = R_G = 576\Omega$ ; unless otherwise specified.

**Frequency Response vs.  $V_{OUT}$**



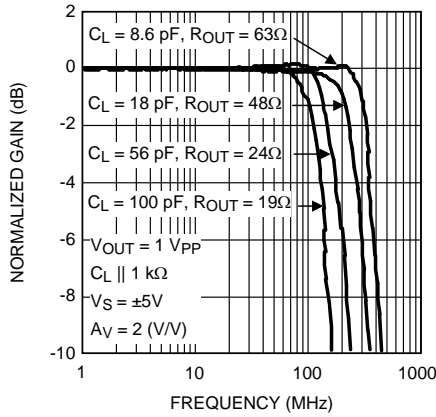
**Figure 2.**

**Frequency Response vs. Gain**



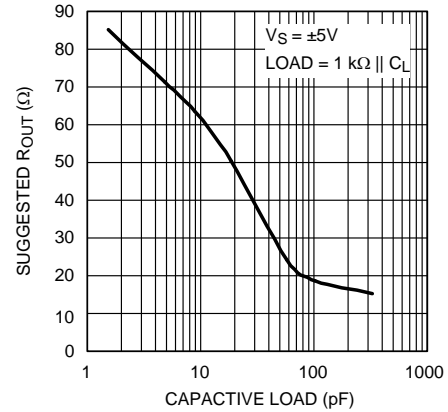
**Figure 3.**

**Frequency Response vs. Capacitive Load**



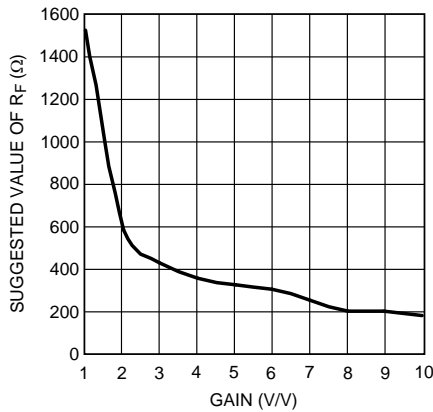
**Figure 4.**

**Suggested ROUT vs. Capacitive Load**



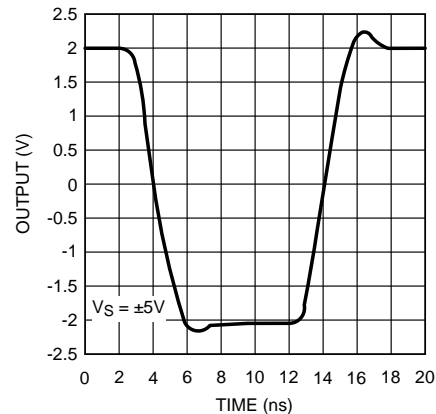
**Figure 5.**

**Suggested Value of RF vs. Gain**



**Figure 6.**

**Pulse Response 4VPP**



**Figure 7.**

Typical Performance Characteristics (continued)

$V_s = \pm 5V$ ,  $R_L = 100\Omega$ ,  $A_v=2$ ,  $R_F=R_G=576\Omega$ ; unless otherwise specified.

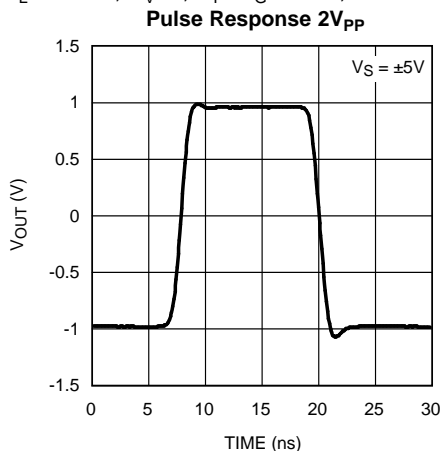


Figure 8.

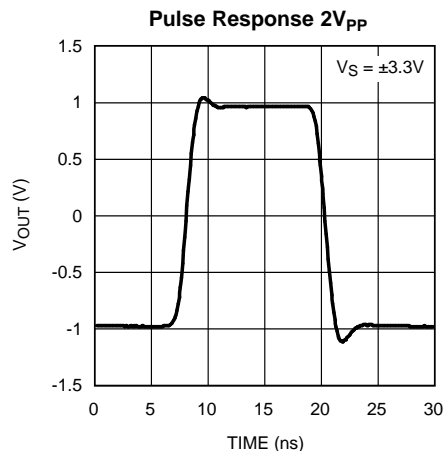


Figure 9.

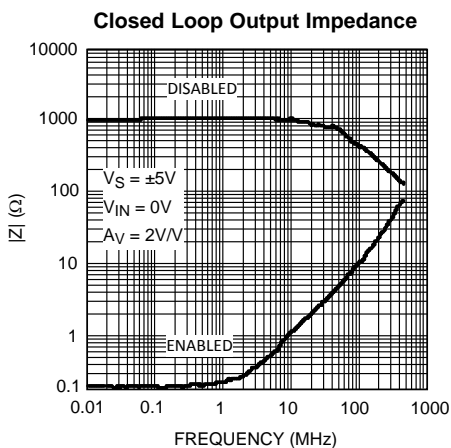


Figure 10.

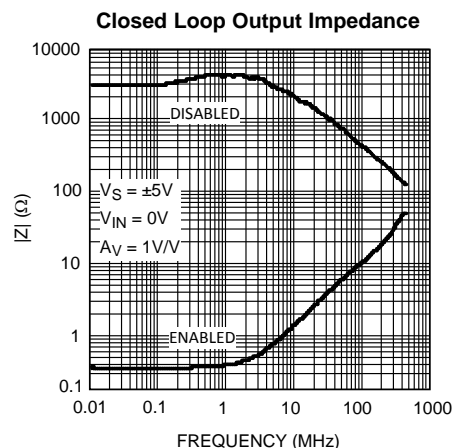


Figure 11.

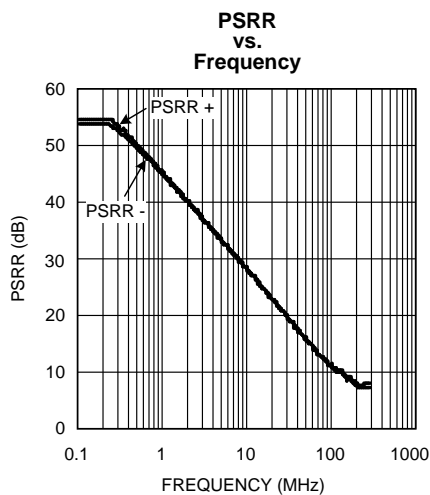


Figure 12.

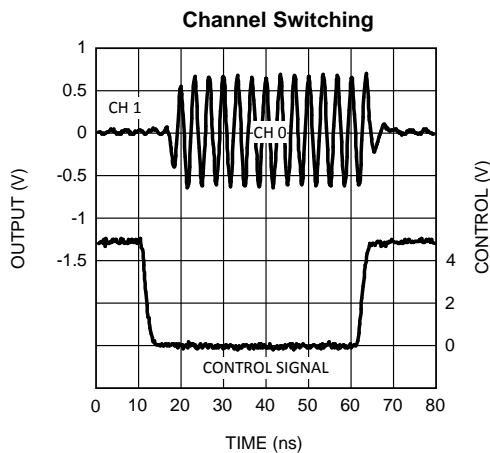
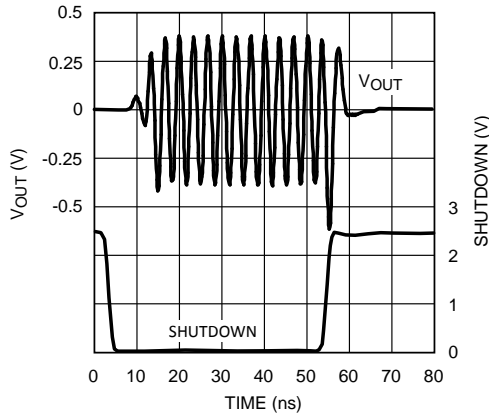


Figure 13.

**Typical Performance Characteristics (continued)**

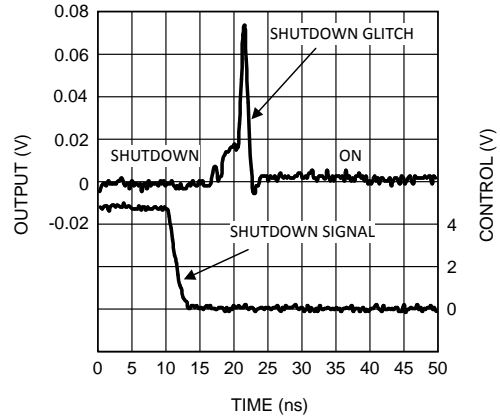
$V_s = \pm 5V$ ,  $R_L = 100\Omega$ ,  $A_V=2$ ,  $R_F=R_G=576\Omega$ ; unless otherwise specified.

**SHUTDOWN Switching**



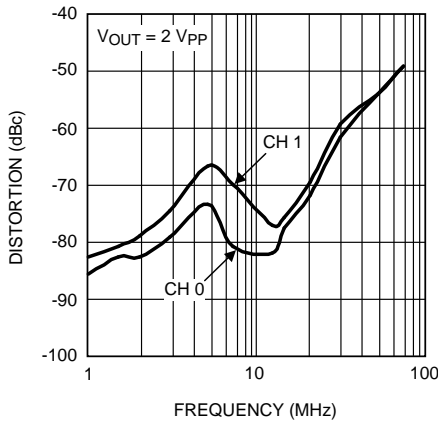
**Figure 14.**

**Shutdown Glitch**



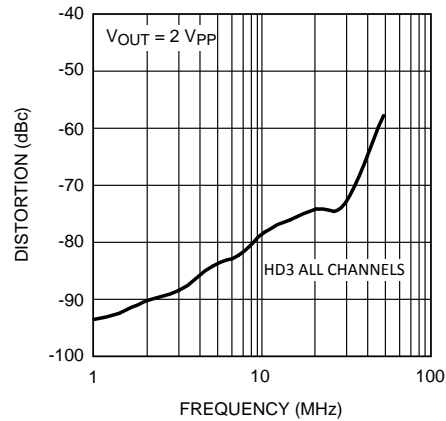
**Figure 15.**

**HD2 vs. Frequency**



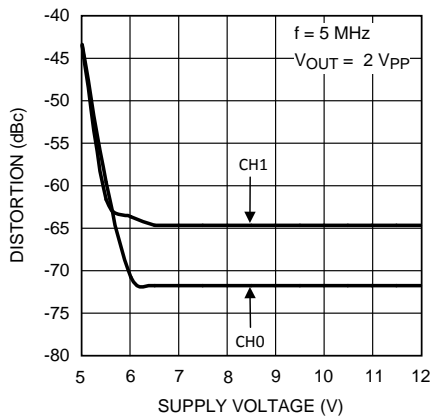
**Figure 16.**

**HD3 vs. Frequency**



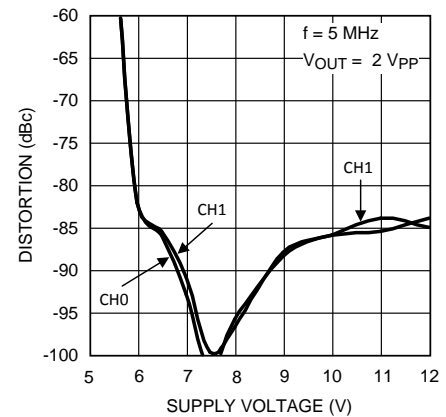
**Figure 17.**

**HD2 vs. Vs**



**Figure 18.**

**HD3 vs. Vs**



**Figure 19.**



**Typical Performance Characteristics (continued)**

$V_s = \pm 5V$ ,  $R_L = 100\Omega$ ,  $A_v=2$ ,  $R_F=R_G=576\Omega$ ; unless otherwise specified.

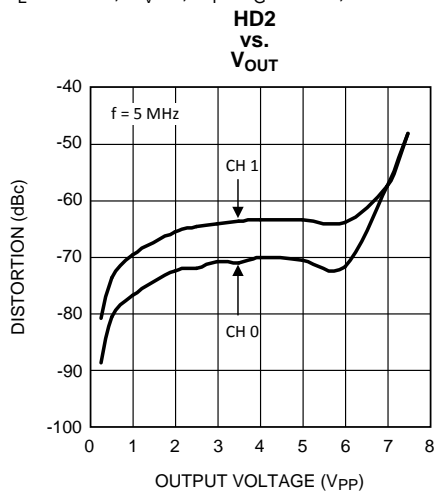


Figure 20.

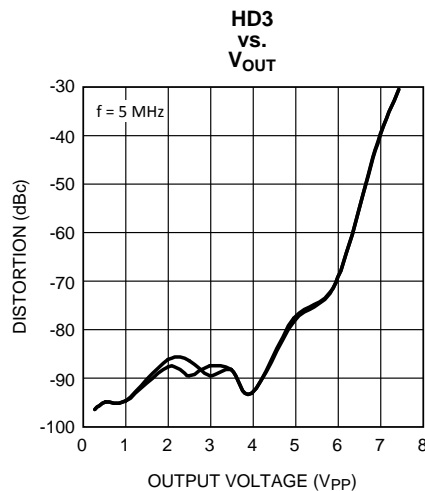


Figure 21.

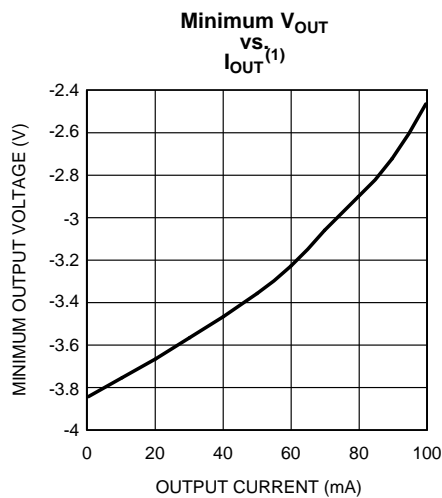


Figure 22.

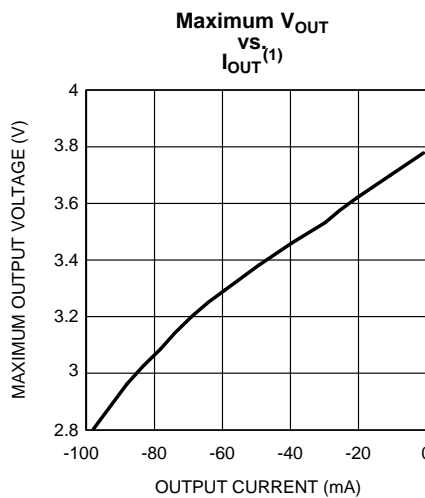


Figure 23.

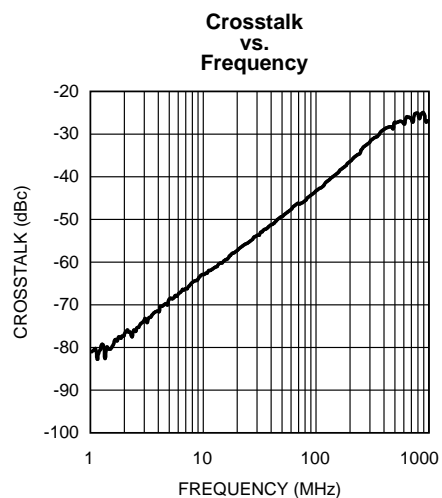


Figure 24.

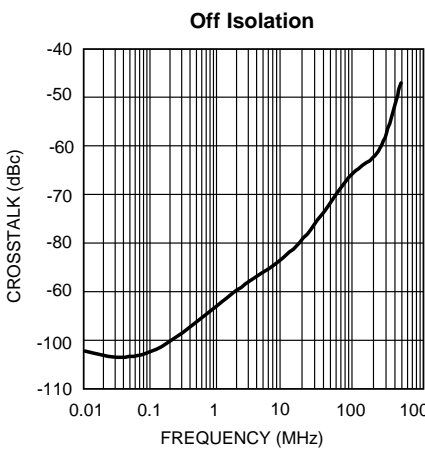
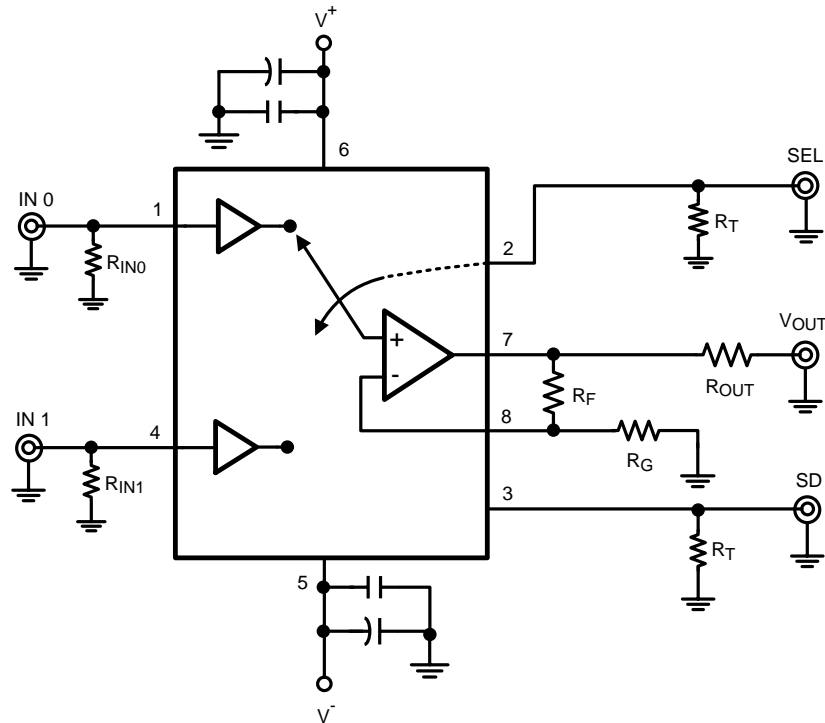


Figure 25.

(1) Positive Value is current into device.

## APPLICATION NOTES

### GENERAL INFORMATION



**Figure 26. Typical Application**

The LMH6570 is a high-speed 2:1 analog multiplexer, optimized for very high speed and low distortion. With selectable gain and excellent AC performance, the LMH6570 is ideally suited for switching high resolution, presentation grade video signals. The LMH6570 has no internal ground reference. Single or split supply configurations are both possible, however, all logic functions are referenced to the mid supply point. The LMH6570 features very high speed channel switching and disable times. When disabled the LMH6570 output is high impedance making MUX expansion possible by combining multiple devices. See [MULTIPLEXER EXPANSION](#). The LMH6570 SEL defaults to logic low (IN0 active). The default state for the SD pin is also logic low (device enabled). Both pins can be left floating if the default state is desired.

### VIDEO PERFORMANCE

The LMH6570 has been designed to provide excellent performance with production quality video signals in a wide variety of formats such as HDTV and High Resolution VGA. Best performance will be obtained with back-terminated loads. The back termination reduces reflections from the transmission line and effectively masks transmission line and other parasitic capacitances from the amplifier output stage. [Figure 26](#) shows a typical configuration for driving a 75Ω cable. The output buffer is configured for a gain of 2, so using back terminated loads will give a net gain of 1.

## FEEDBACK RESISTOR SELECTION

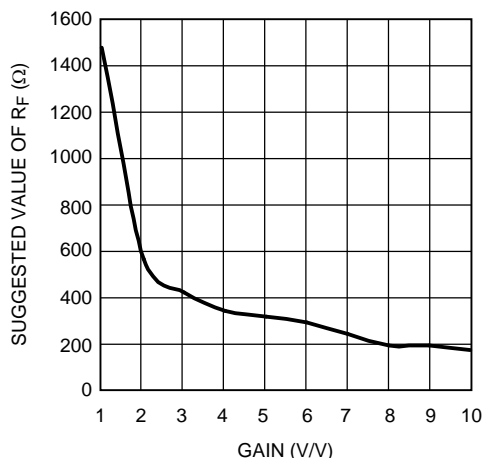


Figure 27. Suggested R<sub>F</sub> vs. Gain

The LMH6570 has a current feedback output buffer with gain determined by external feedback (R<sub>F</sub>) and gain set (R<sub>G</sub>) resistors. With current feedback amplifiers, the closed loop frequency response is a function of R<sub>F</sub>. For a gain of 2 V/V, the recommended value of R<sub>F</sub> is 576Ω. For other gains see Figure 6. Generally, lowering R<sub>F</sub> from the recommended value will peak the frequency response and extend the bandwidth while increasing the value of R<sub>F</sub> will cause the frequency response to roll off faster. Reducing the value of R<sub>F</sub> too far below the recommended value will cause overshoot, ringing and, eventually, oscillation.

Since all applications are slightly different it is worth some experimentation to find the optimal R<sub>F</sub> for a given circuit. For more information see Application Note OA-13 which describes the relationship between R<sub>F</sub> and closed-loop frequency response for current feedback operational amplifiers. The impedance looking into pin 8 is approximately 20Ω. This allows for good bandwidth at gains up to 10 V/V. When used with gains over 10 V/V, the LMH6570 will exhibit a “gain bandwidth product” similar to a typical voltage feedback amplifier. For gains of over 10 V/V consider selecting a high performance video amplifier like the LMH6720 to provide additional gain.

## MULTIPLEXER EXPANSION

With the SHUTDOWN pin putting the output stage into a high impedance state, several LMH6570's can be tied together to form a larger input MUX. However, there is a loading effect on the active output caused by the unselected devices. The circuit in Figure 28 shows how to compensate for this effect. For the 8:1 MUX function shown in Figure 28 below the gain error would be about 0.7% or -0.06dB. In the circuit in Figure 28, resistor ratios have been adjusted to compensate for this gain error. By adjusting the gain of each multiplexer circuit the error can be reduced to the tolerance of the resistors used (1% in this example).

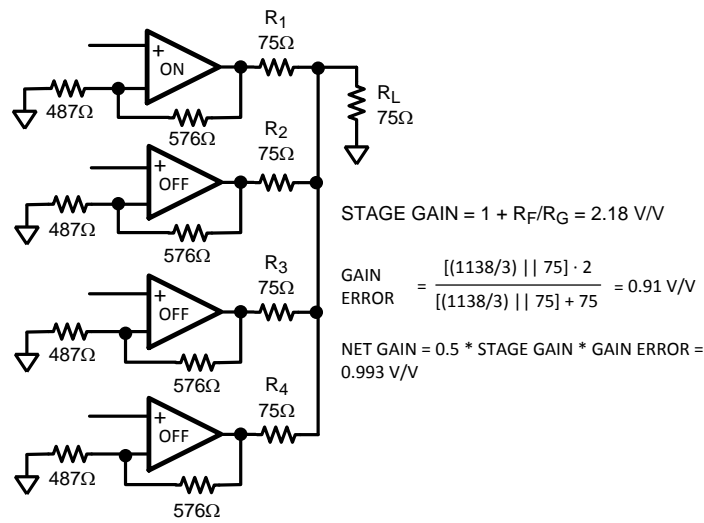


Figure 28. Multiplexer Gain Compensation

**BUILDING A 4:1 MULTIPLEXER**

Figure 29 shows an 4:1 MUX using two LMH6570's.

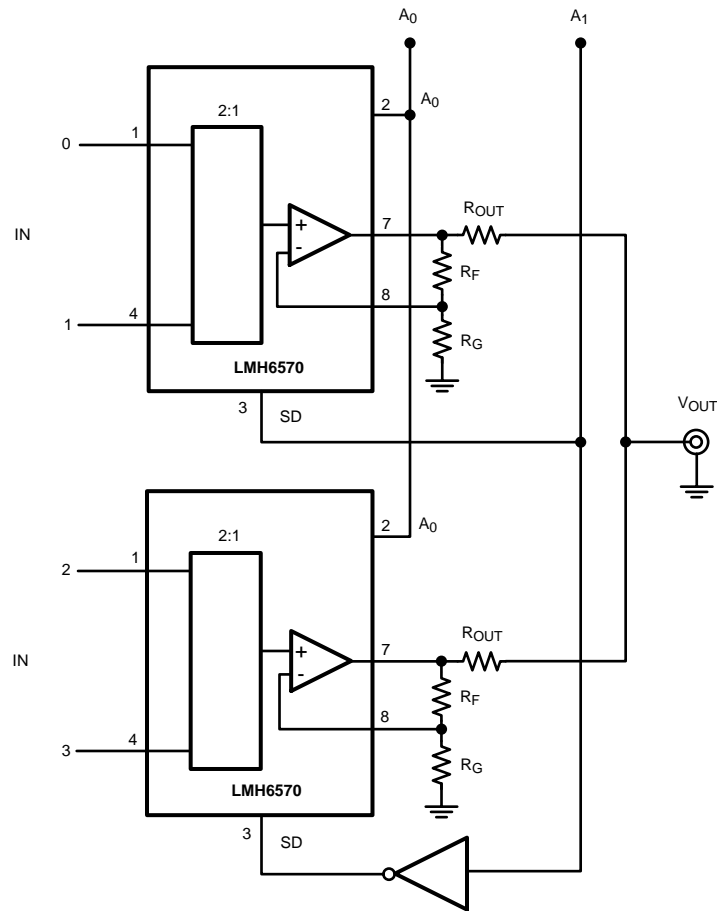


Figure 29. 4:1 MUX USING TWO LMH6570's

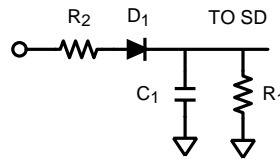


Figure 30. Delay Circuit Implementation

If it is important in the end application to make sure that no two inputs are presented to the output at the same time, an optional delay block can be added, to drive the SHUTDOWN pin of each device, as shown. Figure 30 shows one possible approach to this delay circuit. The delay circuit shown will delay SHUTDOWN's H to L transitions ( $R_1$  and  $C_1$  decay) but won't delay its L to H transition.  $R_2$  should be kept small compared to  $R_1$  in order to not reduce the SHUTDOWN voltage and to produce little or no delay to SHUTDOWN.

### Other Applications

The LMH6570 could support a dual antenna receiver with two physically separate antennas. Monitoring the signal strength of the active antenna and switching to the other antenna when a fade is detected is a simple way to achieve spacial diversity. This method gives about a 3dB boost in average signal strength and is the least expensive method for combining signals.

### DRIVING CAPACITIVE LOADS

Capacitive output loading applications will benefit from the use of a series output resistor  $R_{OUT}$ . Figure 31 shows the use of a series output resistor,  $R_{OUT}$ , to stabilize the amplifier output under capacitive loading. Capacitive loads of 5 to 120 pF are the most critical, causing ringing, frequency response peaking and possible oscillation. Figure 32 gives a recommended value for selecting a series output resistor for mitigating capacitive loads. The values suggested in the charts are selected for 0.5 dB or less of peaking in the frequency response. This gives a good compromise between settling time and bandwidth. For applications where maximum frequency response is needed and some peaking is tolerable, the value of  $R_{OUT}$  can be reduced slightly from the recommended values.

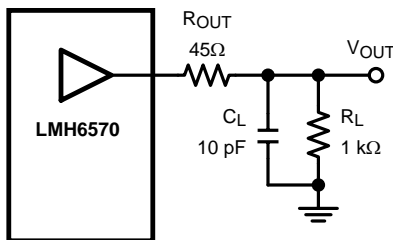


Figure 31. Decoupling Capacitive Loads

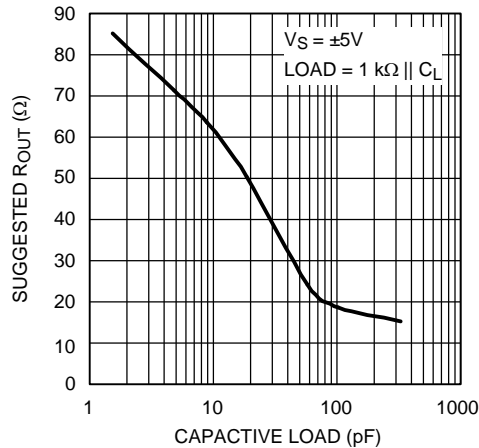
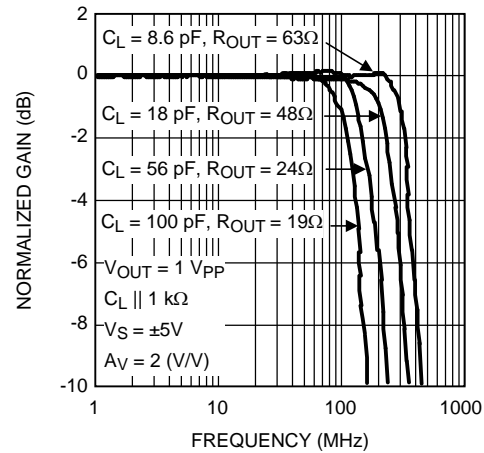
Figure 32. Suggested  $R_{OUT}$  vs. Capacitive Load

Figure 33. Frequency Response vs. Capacitive Load

### LAYOUT CONSIDERATIONS

To reduce parasitic capacitances, ground and power planes should be removed near the input and output pins. For long signal paths controlled impedance lines should be used, along with impedance matching elements at both ends. Bypass capacitors should be placed as close to the device as possible. Bypass capacitors from each rail to ground are applied in pairs. The larger electrolytic bypass capacitors can be located farther from the device, the smaller ceramic capacitors should be placed as close to the device as possible. In [Figure 26](#), the capacitor between  $V^+$  and  $V^-$  is optional, but is recommended for best second harmonic distortion. Another way to enhance performance is to use pairs of  $0.01\mu\text{F}$  and  $0.1\mu\text{F}$  ceramic capacitors for each supply bypass.

### POWER DISSIPATION

The LMH6570 is optimized for maximum speed and performance in the small form factor of the standard SOIC package. To ensure maximum output drive and highest performance, thermal shutdown is not provided. Therefore, it is of utmost importance to make sure that the  $T_{JMAX}$  is never exceeded due to the overall power dissipation.

Follow these steps to determine the maximum power dissipation for the LMH6570:

1. Calculate the quiescent (no-load) power:

$$P_{AMP} = I_{CC} * (V_S),$$

where

- $V_S = V^+ - V^-$  (1)

2. Calculate the RMS power dissipated in the output stage:

$$P_D (rms) = rms ((V_S - V_{OUT}) * I_{OUT})$$

where

- $V_{OUT}$  and  $I_{OUT}$  are the voltage across
- The current through the external load and  $V_S$  is the total supply voltage (2)

3. Calculate the total RMS power:

$$P_T = P_{AMP} + P_D (3)$$

The maximum power that the LMH6570 package can dissipate at a given temperature can be derived with the following equation:

$$P_{MAX} = (150^\circ - T_{AMB}) / \theta_{JA}$$

where

- $T_{AMB}$  = Ambient temperature ( $^\circ\text{C}$ )
- $\theta_{JA}$  = Thermal resistance, from junction to ambient, for a given package ( $^\circ\text{C}/\text{W}$ )
- For the SOIC package  $\theta_{JA}$  is  $150^\circ\text{C}/\text{W}$  (4)

## ESD PROTECTION

The LMH6570 is protected against electrostatic discharge (ESD) on all pins. The LMH6570 will survive 2000V Human Body model and 200V Machine model events. Under normal operation the ESD diodes have no effect on circuit performance. There are occasions, however, when the ESD diodes will be evident. If the LMH6570 is driven by a large signal while the device is powered down the ESD diodes will conduct. The current that flows through the ESD diodes will either exit the chip through the supply pins or will flow through the device, hence it is possible to power up a chip with a large signal applied to the input pins. Using the shutdown mode is one way to conserve power and still prevent unexpected operation.

## REVISION HISTORY

Changes from Revision B (April 2013) to Revision C	Page
• Changed layout of National Data Sheet to TI format .....	15



**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LMH6570MA/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMH6570MA	<a href="#">Samples</a>
LMH6570MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMH6570MA	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMH6570MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMH6570MAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AA.

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